NSN 5961-00-136-4910

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-136-4910 **Inclosure Material:** Glass **Overall Length:** Between 0.195 inches and 0.350 inches **Terminal Length:** 1.000 inches **Overall Diameter:** Between 0.215 inches and 0.265 inches **Function For Which Designed:** Zener diode **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 36.0 regulator voltage **Voltage Tolerance In Percent:** -5.0 to 5.0 **Current Rating Per Characteristic:** 26.00 milliamperes repetitive peak forward current and 130.00 milliamperes forward current, average pascal **Power Rating Per Characteristic:** 1.0 watts total device dissipation **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius ambient air **Special Test Features:** Power surge to 3000 watts iaw mis-14150/51 **Test Data Document:** 81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Terminal Type And Quantity:** 2 uninsulated wire lead **Specification Data:** 81349-mil-s-19500/115 government specification Shelf Life: N/a **Unit Of Measure: Demilitarization:**

No

Fiig:

A110a0